

电位移矢量 $\vec{D} = \epsilon_0 \epsilon_r \vec{E} = \epsilon \vec{E}$ (均匀各同性介质)

有介质时的高斯定理 $\oint_S \vec{D} \cdot d\vec{S} = \sum_i Q_{oi}$

$$\vec{D} = \begin{cases} \vec{P} + \epsilon_0 \vec{E} & (\text{任何介质}) \\ \epsilon \vec{E} & (\text{均匀介质}) \end{cases}$$

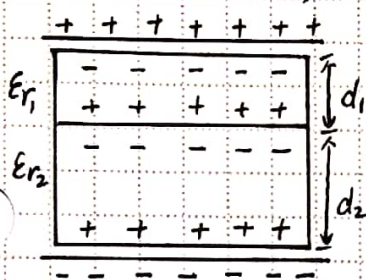
~~$\oint_S \vec{D} \cdot d\vec{S} = Q_0$~~ 在上-例中.

$$\oint_S \vec{D} \cdot d\vec{S} = Q_0$$

$$D S = \epsilon_0 S$$

$$D = \epsilon_0$$

例: 求 ϵ_1, ϵ_2

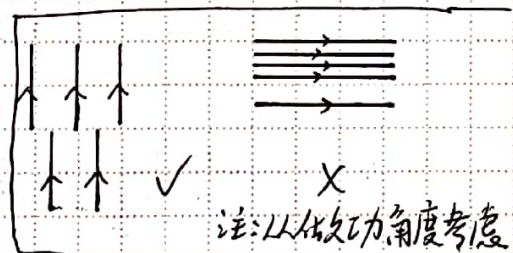


$$\epsilon_1' = \frac{\epsilon_{r1} - 1}{\epsilon_{r1}} \epsilon_0$$

$$\epsilon_2' = \frac{\epsilon_{r2} - 1}{\epsilon_{r2}} \epsilon_0$$

$$D = \epsilon \vec{E} = \epsilon_0 \epsilon_r \frac{E_0}{\epsilon_r} = \epsilon_0 E_0$$

上下 E 不连续, D 是一样的.



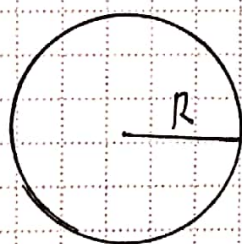
2.2 电容和电容器

一. 电容

$$C = \frac{Q}{\varphi}, \text{ 选 } \varphi_\infty = 0$$

(φ 也可写成 V)

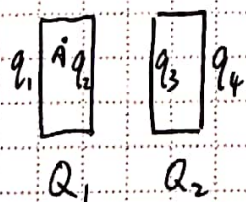
单位 $1F = 1C/V$
 $1\mu F = 10^{-6}F$
 $1pF = 10^{-12}F$



$$\varphi = \begin{cases} k \frac{Q}{R} & (r \leq R) \\ k \frac{Q}{r} & (r > R) \end{cases}$$

孤立导体球电容 $C = \frac{Q}{V} = \frac{Q}{k \frac{Q}{R}} = \frac{R}{k} = 4\pi \epsilon_0 R$

电容器电容 $C = \frac{Q}{\varphi_A - \varphi_B} = \frac{Q}{U}$ 指的是 $|q_2|$ or $|q_3|$



法一: $\begin{cases} q_1 + q_2 = Q_1 \\ q_3 + q_4 = Q_2 \\ q_2 + q_3 = 0 \rightarrow \text{发射电场线数目} = \text{接收电场线数目} \\ q_1 + q_4 = q_4 \rightarrow A \text{ 点 } E = 0 \end{cases}$

$$\Rightarrow \begin{cases} q_1 = q_4 = \frac{Q_1 + Q_2}{2} \\ q_2 = -q_3 = \frac{Q_1 - Q_2}{2} \end{cases}$$

法二:

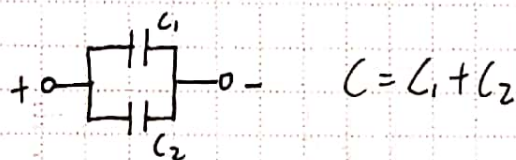
$$\begin{array}{|c|} \hline Q_1, Q_2 \\ \hline \end{array} \Rightarrow \begin{array}{|c|} \hline Q_1 + Q_2 \\ \hline \end{array}$$

近似

故 $q_1 = q_4 = \frac{Q_1 + Q_2}{2}$

最外的面的电荷量一定是总电荷的一半。

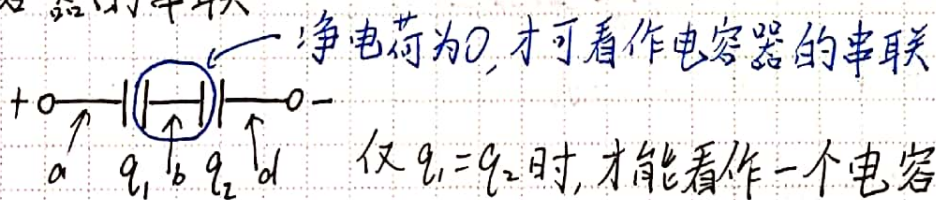
电容器的并联



证明: $C_{\text{总}} U = Q_{\text{总}} = q_1 + q_2 = C_1 U + C_2 U = (C_1 + C_2) U$

注: 也是并联

电容器的串联

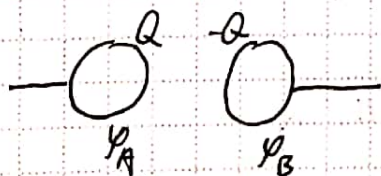


证: 若 $q_1 = q_2 = q$

$$U_{ad} = U_{ab} + U_{bd}$$

$$\frac{q}{C_{\text{总}}} = \frac{q_1}{C_1} + \frac{q_2}{C_2}$$

$$\therefore C_{\text{总}} = \frac{C_1 C_2}{C_1 + C_2}$$



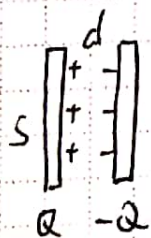
$$C_1 = \frac{Q}{\phi_A}$$

$$C_2 = -\frac{Q}{\phi_B}$$

$$C = \frac{Q}{\phi_A - \phi_B}$$

$\therefore C$ 与电荷量无关

一、平行板电容器



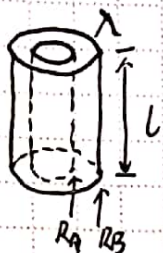
$$E = \frac{\sigma}{\epsilon_0} = \frac{Q}{\epsilon_0 S}$$

$$U = Ed = \frac{Qd}{\epsilon_0 S}$$

$$C = \frac{Q}{U} = \epsilon_0 \frac{S}{d}$$

有电介质 $C = \frac{\epsilon_0 \epsilon_r S}{d} = \frac{\epsilon_r S}{4\pi k d}$

二. 圆柱形电容器



$$E = \frac{\lambda}{2\pi\epsilon_0 r} \quad (R_A < r < R_B)$$

$$U = \int_{R_A}^{R_B} \frac{\lambda}{2\pi\epsilon_0} \frac{1}{r} dr = \frac{\lambda}{2\pi\epsilon_0} \ln r \Big|_{R_A}^{R_B} = \frac{\lambda}{2\pi\epsilon_0} \ln \frac{R_B}{R_A}$$

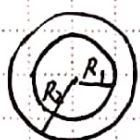
$$C = \frac{Q}{U} = \frac{\lambda L}{U} = \frac{\lambda L}{\frac{\lambda}{2\pi\epsilon_0} \ln \frac{R_B}{R_A}} = \frac{2\pi\epsilon_0 L}{\ln \frac{R_B}{R_A}}$$

$$\ln \frac{R_B}{R_A} \approx \frac{R_B - R_A}{R_A} \quad \text{when } R_B - R_A \ll R_A$$

$$C \approx \frac{2\pi\epsilon_0 L R_A}{R_B - R_A} = \frac{\epsilon_0 S}{d}$$

$$\lim_{x \rightarrow 0} \ln(1+x) \sim x$$

三. 球形电容器



$$\vec{E} = \frac{Q}{4\pi\epsilon_0 r^2} \cdot \vec{e}_r \quad (R_1 < r < R_2)$$

$$U = \int_{R_1}^{R_2} \vec{E} \cdot d\vec{l} = \frac{Q}{4\pi\epsilon_0} \int_{R_1}^{R_2} \frac{dr}{r^2} = \frac{Q}{4\pi\epsilon_0} \left(\frac{1}{R_1} - \frac{1}{R_2} \right)$$

$$\varphi = \begin{cases} k\frac{Q}{r} & r \leq R \\ k\frac{Q}{R} & r > R \end{cases}$$

$$U = kQ \left(\frac{1}{R_1} - \frac{1}{R_2} \right)$$

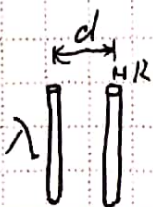
$$\therefore C = 4\pi\epsilon_0 \frac{R_1 R_2}{R_2 - R_1}$$

$$R_2 - R_1 \ll R_1$$

$$C \approx \frac{\epsilon_0 4\pi R_1 R_2}{R_2 - R_1} \approx \frac{\epsilon_0 S}{d}$$

$R_2 \rightarrow \infty$, $C = 4\pi\epsilon_0 R_1$ ← 孤立导体球电容

孤立导体电容可看作另一极板在无穷远处时的电容器



$$\vec{E} = \frac{\lambda}{2\pi\epsilon r} + \frac{\lambda}{2\pi\epsilon(d-r)}$$

$$U = \int_R^{d-R} \left(\frac{\lambda}{2\pi\epsilon r} + \frac{\lambda}{2\pi\epsilon(d-r)} \right) dr = \frac{\lambda}{2\pi\epsilon} \ln \frac{d-R}{R} - \frac{\lambda}{2\pi\epsilon} \ln \frac{R}{d-R} \approx \frac{\lambda}{\pi\epsilon_0} \ln \frac{d}{R}$$

法二: $E_1 = \frac{\lambda}{2\pi\epsilon r}$

$$U = 2 \int_R^{d-R} \frac{\lambda}{2\pi\epsilon r} dr = \frac{\lambda}{\pi\epsilon} \ln \frac{d-R}{R} \approx \frac{\lambda}{\pi\epsilon} \ln \frac{d}{R}$$

$$C = \frac{\pi\epsilon_0}{\ln \frac{d}{R}}$$

电场能量

$U \quad \downarrow E \quad \uparrow dq$

$$dW = dq \cdot E \cdot d = dq \cdot U = dq \cdot \frac{q}{C}$$

$$W = \frac{1}{C} \int_0^Q q dq = \frac{Q^2}{2C} = \frac{1}{2} QU = \frac{1}{2} CU^2$$

$C = \frac{Q}{U}$

$$W_e = \frac{1}{2} CU^2 = \frac{1}{2} \frac{\epsilon S}{d} (Ed)^2 = \left[\frac{1}{2} \epsilon E^2 \right] S d$$

$$W_e = \frac{1}{2} \epsilon \vec{E}^2 = \frac{1}{2} \vec{E} \cdot \vec{D}$$

电场能量密度 只适用于 各向同性电介质 适用于任意电介质

物理意义: 电场是一种物质, 它具有能量

$$W_e = \int_V w_e dV = \int_V \frac{1}{2} \epsilon E^2 dV$$

体积分

例: 球形电容器的内外半径分别为 R_1 和 R_2 , 所带电荷为 $\pm Q$, 若
在两球壳间充以电容率为 ϵ 的电介质, 问此电容器贮存的电
场能量为多少.



解: $\vec{E} = \frac{1}{4\pi\epsilon} \frac{Q}{r^2} \vec{e}_r$

$$w_e = \frac{1}{2} \epsilon E^2 = \frac{Q^2}{32\pi^2 \epsilon r^4}$$

$$dW_e = w_e dV = \frac{Q^2}{8\pi\epsilon r^2} dr$$

$$W_e = \int dW_e = \frac{Q^2}{8\pi\epsilon} \int_{R_1}^{R_2} \frac{dr}{r^2} = \frac{Q^2}{8\pi\epsilon} \left(\frac{1}{R_1} - \frac{1}{R_2} \right)$$

法二: $U = kQ \left(\frac{1}{R_1} - \frac{1}{R_2} \right)$, $W_e = \frac{1}{2} QU = \frac{1}{2} Q^2 \left(\frac{1}{R_1} - \frac{1}{R_2} \right)$